# NSN 5962-01-031-1919

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# **Body Length:**

Between 0.755 inches and 0.785 inches

# **Body Width:**

Between 0.220 inches and 0.280 inches

# **Body Height:**

Between 0.140 inches and 0.180 inches

# **Maximum Power Dissipation Rating:**

500.0 milliwatts

# **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

# End Application:

Digital data set type an/fsq-111 fscm 81995

# **Features Provided:**

Hermetically sealed and high speed and monolithic and bipolar and positive outputs and programmable and w/decoded output and w/enable

and 3-state output

# **Inclosure Material:**

Ceramic and glass

# Inclosure Configuration:

Dual-in-line

#### Output Logic Form:

Transistor-transistor logic

#### Input Circuit Pattern:

6 input

#### **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-1.0 volts power source and 5.5 volts power source

## Time Rating Per Chacteristic:

35.00 nanoseconds propagation delay time, low to high level output

## Memory Device Type:

Rom

# Memory Capacity:

Unknown

# **Terminal Type And Quantity:**

16 printed circuit

## Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

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